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HMC530* Product Page Quick Links

Last Content Update: 11/01/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits <a> □

• HMC530LP5 Evaluation Board

Documentation <a>□

Data Sheet

• HMC530 Data Sheet

Reference Materials 🖵

Quality Documentation

- Package/Assembly Qualification Test Report: 32L 5x5mm QFN Package (QTR: 10009 REV: 05)
- Package/Assembly Qualification Test Report: LP3, LP4, LP5 & LP5G (QTR: 2014-00145)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

Design Resources -

- HMC530 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- · Symbols and Footprints

Discussions <a>□

View all HMC530 EngineerZone Discussions

Sample and Buy 🖳

Visit the product page to see pricing options

Technical Support <a> □

Submit a technical question or find your regional support number

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HMC530LP5 / 530LP5E



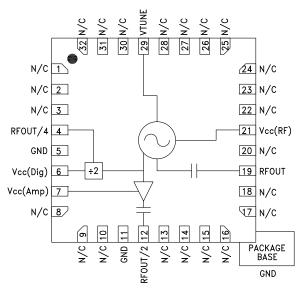
MMIC VCO w/ HALF FREQUENCY OUTPUT & DIVIDE-BY-4, 9.5 - 10.8 GHz

Typical Applications

Low noise MMIC VCO w/Half Frequency, Divide-by-4 Outputs for:

- Point to Point/Multipoint Radio
- Test Equipment & Industrial Controls
- SATCOM
- · Military End-Use

Functional Diagram



Features

Triple Output: Fo = 9.5 - 10.8 GHz Fo/2 = 4.75 - 5.4 GHzFo/4 = 2.38 - 2.7 GHz

Pout: +11 dBm

Phase Noise: -110 dBc/Hz @100 kHz Typ.

No External Resonator Needed

32 Lead 5 x 5 mm SMT Package: 25 mm2

General Description

The HMC530LP5 & HMC530LP5E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC530LP5 & HMC530LP5E integrate resonators, negative resistance devices, varactor diodes and feature half frequency and divide-by-4 outputs. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +11 dBm typical from a +5V supply voltage. The prescaler and RF/2 functions can be disabled to conserve current if not required. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

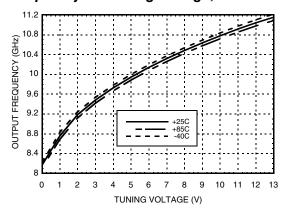
Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vcc (Dig), Vcc (Amp), Vcc (RF) = +5V

Parameter		Min.	Тур.	Max.	Units
Frequency Range	Fo Fo/2		9.5 - 10.8 4.75 - 5.4		GHz GHz
Power Output	RFOUT/2 RFOUT/4	+8 +8 -8		+14 +14 -3	dBm dBm dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RFOUT			-110		dBc/Hz
Tune Voltage	Vtune	2		12	V
Supply Current	Icc(Dig) + Icc(Amp) + Icc(RF)	290	350	390	mA
Tune Port Leakage Current (Vtune= 13V)				10	μA
Output Return Loss			5		dB
Harmonics/Subharmonics	1/2 2nd 3rd		30 20 30		dBc dBc dBc
Pulling (into a 2.0:1 VSWR)			7		MHz pp
Pushing @ Vtune= 5V			20		MHz/V
Frequency Drift Rate	<u> </u>		1		MHz/°C

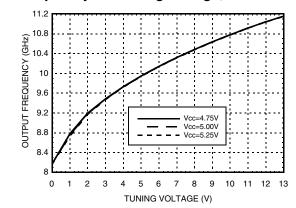




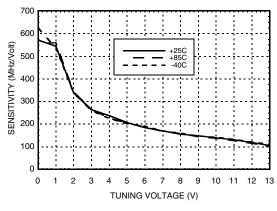
Frequency vs. Tuning Voltage, Vcc = +5V



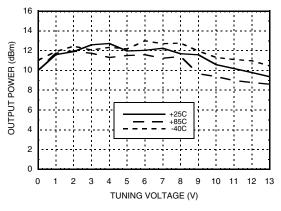
Frequency vs. Tuning Voltage, T= 25°C



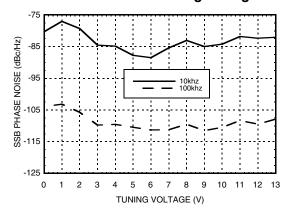
Sensitivity vs. Tuning Voltage, Vcc = +5V



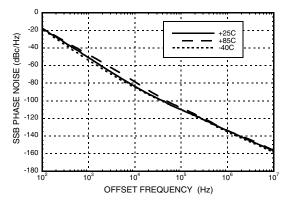
Output Power vs. Tuning Voltage, Vcc = +5V



SSB Phase Noise vs. Tuning Voltage



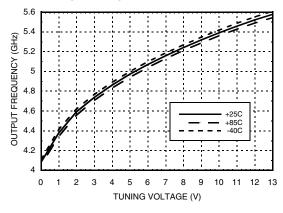
SSB Phase Noise @ Vtune = +5V



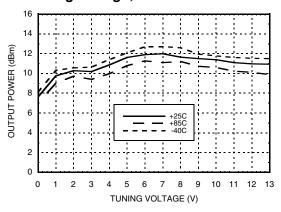




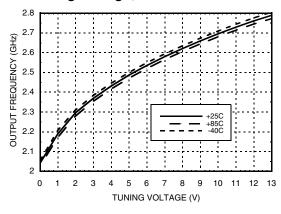
RFOUT/2 Frequency vs. Tuning Voltage, Vcc = +5V



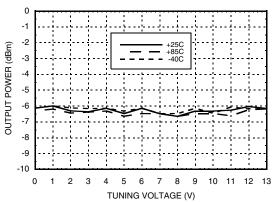
RFOUT/2 Output Power vs. Tuning Voltage, Vcc = +5V



Divide-by-4 Frequency vs. Tuning Voltage, Vcc = +5V



Divide-by-4 Output Power vs. Tuning Voltage, Vcc = +5V



Absolute Maximum Ratings

Vcc(Dig), Vcc(Amp), Vcc(RF)	+5.5 Vdc
Vtune	0 to +15V
Junction Temperature	135 °C
Continuous Pdiss (T=85 °C) (derate 43.5 mW/C above 85 °C	2.17 W
Thermal Resistance (junction to ground paddle)	23 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
4.75	320
5.00	350
5.25	380

Note: VCO will operate over full voltage range shown above.

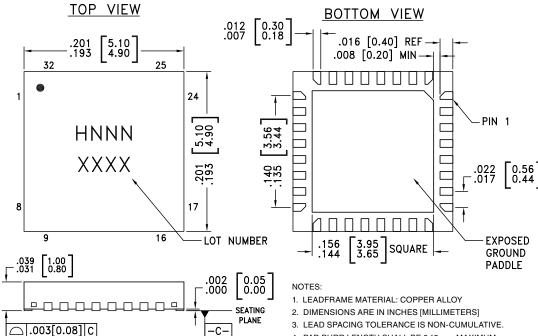


ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS





Outline Drawing



- 4. PAD BURR LENGTH SHALL BE 0.15 mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05 mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05 mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC530LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL3 [1]	H530 XXXX
HMC530LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 [2]	<u>H530</u> XXXX

- [1] Max peak reflow temperature of 235 $^{\circ}\text{C}$
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX

Pin Descriptions

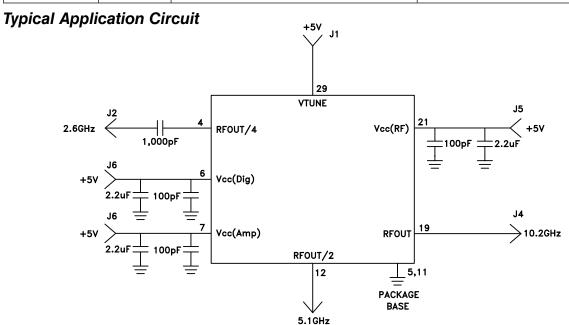
Pin Number	Function	Description	Interface Schematic
1 - 3, 8 - 10, 13 - 18, 20, 22 - 28, 30 - 32	N/C	No Connection. These pins may be connected to RF/DC ground. Performance will not be affected.	
4	RFOUT/4	Divide-by-4 output. DC block required.	5V RFOUT/4
6	Vcc (Dig)	Supply voltage for prescaler. If prescaler is not required, this pin may be left open to conserve approximately 65 mA of current.	Vcc(Dig) 14pF





Pin Descriptions

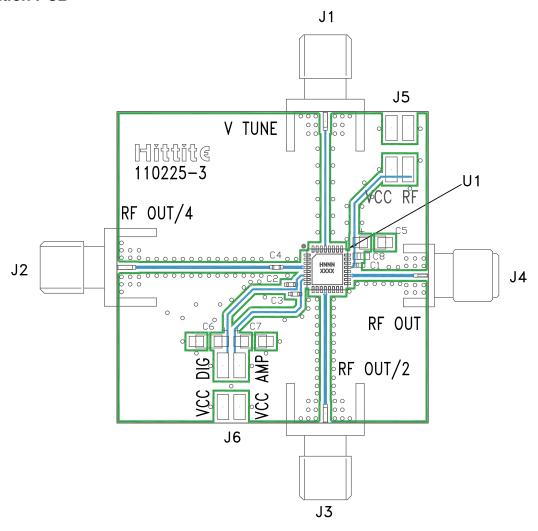
Pin Number	Function	Description	Interface Schematic
7	Vcc (Amp)	Supply voltage for RFOUT/2 output. If RFOUT/2 is not required, this pin may be left open to conserve approximately 30 mA of current.	Vcc(Amp) 14pF
12	RFOUT/2	Half frequency output (AC coupled).	PO RFOUT/2
19	RF OUT	RF output (AC coupled).	RFOUT
21	Vcc (RF)	Supply Voltage, +5V	Vcc(RF)
29	VTUNE	Control voltage and modulation input. Modulation bandwidth dependent on drive source impedance. See "Determining the FM Bandwidth of a Wideband Varactor Tuned VCO" application note.	VTUNE O 53pF
5, 11, Paddle	GND	Package bottom has an exposed metal paddle that must be connected to RF/DC ground.	GND =







Evaluation PCB



List of Materials for Evaluation PCB 110227 [1]

Item	Description	
J1 - J4	PCB Mount SMA RF Connector	
J5 - J6	2 mm DC Header	
C1 - C3	100 pF Capacitor, 0402 Pkg.	
C4	1,000 pF Capacitor, 0402 Pkg.	
C5 - C7	2.2 µF Tantalum Capacitor	
U1	HMC530LP5(E) VCO	
PCB [2]	110225 Eval Board	

^[1] Reference this number when ordering complete evaluation PCB $\,$

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and backside ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Arlon 25FR